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Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	32MHz
Connectivity	I ² C, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	16
Program Memory Size	7KB (4K x 14)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	384 x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 12x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SSOP (0.209", 5.30mm Width)
Supplier Device Package	20-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16lf1827-e-ss

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Name	Function	Input Type	Output Type	Description
RA0/AN0/CPS0/C12IN0-/	RA0	TTL	CMOS	General purpose I/O.
SDO2 ⁽²⁾	AN0	AN	_	A/D Channel 0 input.
	CPS0	AN	_	Capacitive sensing input 0.
	C12IN0-	AN	_	Comparator C1 or C2 negative input.
	SDO2		CMOS	SPI data output.
RA1/AN1/CPS1/C12IN1-/SS2 ⁽²⁾	RA1	TTL	CMOS	General purpose I/O.
	AN1	AN	—	A/D Channel 1 input.
	CPS1	AN	—	Capacitive sensing input 1.
	C12IN1-	AN	—	Comparator C1 or C2 negative input.
	SS2	ST	—	Slave Select input 2.
RA2/AN2/CPS2/C12IN2-/	RA2	TTL	CMOS	General purpose I/O.
C12IN+/VREF-/DACOUT	AN2	AN	—	A/D Channel 2 input.
	CPS2	AN	—	Capacitive sensing input 2.
	C12IN2-	AN	_	Comparator C1 or C2 negative input.
	C12IN+	AN	—	Comparator C1 or C2 positive input.
	VREF-	AN	—	A/D Negative Voltage Reference input.
	DACOUT	—	AN	Voltage Reference output.
RA3/AN3/CPS3/C12IN3-/C1IN+/	RA3	TTL	CMOS	General purpose I/O.
VREF+/C1OUT/CCP3 ⁽²⁾ /SRQ	AN3	AN	—	A/D Channel 3 input.
	CPS3	AN	_	Capacitive sensing input 3.
	C12IN3-	AN	—	Comparator C1 or C2 negative input.
	C1IN+	AN	—	Comparator C1 positive input.
	VREF+	AN	_	A/D Voltage Reference input.
	C10UT	_	CMOS	Comparator C1 output.
	CCP3	ST	CMOS	Capture/Compare/PWM3.
	SRQ	—	CMOS	SR latch non-inverting output.
RA4/AN4/CPS4/C2OUT/T0CKI/	RA4	TTL	CMOS	General purpose I/O.
CCP4 ⁽²⁾ /SRNQ	AN4	AN		A/D Channel 4 input.
	CPS4	AN	_	Capacitive sensing input 4.
	C2OUT	—	CMOS	Comparator C2 output.
	TOCKI	ST	—	Timer0 clock input.
	CCP4	ST	CMOS	Capture/Compare/PWM4.
	SRNQ	—	CMOS	SR latch inverting output.
RA5/MCLR/VPP/SS1 ^(1,2)	RA5	TTL	CMOS	General purpose I/O.
	MCLR	ST		Master Clear with internal pull-up.
	VPP	HV	_	Programming voltage.
	SS1	ST	_	Slave Select input 1.

TABLE 1-2: PIC16(L)F1826/27 PINOUT DESCRIPTION

Legend: AN = Analog input or output CMOS = CMOS compatible input or output OD = Open Drain TTL = TTL compatible input ST = Schmitt Trigger input with CMOS levels I^2C^{TM} = Schmitt Trigger input with I^2C HV = High Voltage XTAL = Crystal levels

Note 1: Pin functions can be moved using the APFCON0 or APFCON1 register.

2: Functions are only available on the PIC16(L)F1827.

3: Default function location.

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Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on POR, BOR	Value on all other Resets
Bank 4											
20Ch	WPUA	—	—	WPUA5	—	—	—	—	_	1	1
20Dh	WPUB	WPUB7	WPUB6	WPUB5	WPUB4	WPUB3	WPUB2	WPUB1	WPUB0	1111 1111	1111 1111
20Eh	—	Unimplement	ted							—	—
20Fh	—	Unimplement	ted							—	—
210h	—	Unimplement	ted							—	—
211h	SSP1BUF	Synchronous	Serial Port R	eceive Buffer/7	Fransmit Regis	ster				XXXX XXXX	uuuu uuuu
212h	SSP1ADD	ADD7	ADD6	ADD5	ADD4	ADD3	ADD2	ADD1	ADD0	0000 0000	0000 0000
213h	SSP1MSK	MSK7	MSK6	MSK5	MSK4	MSK3	MSK2	MSK1	MSK0	1111 1111	1111 1111
214h	SSP1STAT	SMP	CKE	D/A	Р	S	R/W	UA	BF	0000 0000	0000 0000
215h	SSP1CON1	WCOL	SSPOV	SSPEN	CKP	SSPM3	SSPM2	SSPM1	SSPM0	0000 0000	0000 0000
216h	SSP1CON2	GCEN	ACKSTAT	ACKDT	ACKEN	RCEN	PEN	RSEN	SEN	0000 0000	0000 0000
217h	SSP1CON3	ACKTIM	PCIE	SCIE	BOEN	SDAHT	SBCDE	AHEN	DHEN	0000 0000	0000 0000
218h	—	Unimplement	nimplemented							_	_
219h	SSP2BUF ⁽¹⁾	Synchronous	Synchronous Serial Port Receive Buffer/Transmit Register							xxxx xxxx	uuuu uuuu
21Ah	SSP2ADD ⁽¹⁾	ADD7	ADD6	ADD5	ADD4	ADD3	ADD2	ADD1	ADD0	0000 0000	0000 0000
21Bh	SSP2MSK ⁽¹⁾	MSK7	MSK6	MSK5	MSK4	MSK3	MSK2	MSK1	MSK0	1111 1111	1111 1111
21Ch	SSP2STAT ⁽¹⁾	SMP	CKE	D/A	Р	S	R/W	UA	BF	0000 0000	0000 0000
21Dh	SSP2CON1(1)	WCOL	SSPOV	SSPEN	CKP	SSPM3	SSPM2	SSPM1	SSPM0	0000 0000	0000 0000
21Eh	SSP2CON2 ⁽¹⁾	GCEN	ACKSTAT	ACKDT	ACKEN	RCEN	PEN	RSEN	SEN	0000 0000	0000 0000
21Fh	SSP2CON3(1)	ACKTIM	PCIE	SCIE	BOEN	SDAHT	SBCDE	AHEN	DHEN	0000 0000	0000 0000
Bank 5	i	•	•	•		•			•	•	
28Ch	_	Unimplement	ted							_	_
28Dh	_	Unimplement	ted							_	_
28Eh		Unimplement	ted							_	_
28Fh	_	Unimplement	ted							_	_
290h	_	Unimplement	ted							_	_
291h	CCPR1L	Capture/Com	pare/PWM Re	egister 1 (LSB))					xxxx xxxx	uuuu uuuu
292h	CCPR1H	Capture/Com	pare/PWM Re	egister 1 (MSB	5)					xxxx xxxx	uuuu uuuu
293h	CCP1CON	P1M1	P1M0	DC1B1	DC1B0	CCP1M3	CCP1M2	CCP1M1	CCP1M0	0000 0000	0000 0000
294h	PWM1CON	P1RSEN	P1DC6	P1DC5	P1DC4	P1DC3	P1DC2	P1DC1	P1DC0	0000 0000	0000 0000
295h	CCP1AS	CCP1ASE	CCP1AS2	CCP1AS1	CCP1AS0	PSS1AC1	PSS1AC0	PSS1BD1	PSS1BD0	0000 0000	0000 0000
296h	PSTR1CON	—	—	—	STR1SYNC	STR1D	STR1C	STR1B	STR1A	0 0001	0 0001
297h	—	Unimplement	ted							_	_
298h	CCPR2L ⁽¹⁾	Capture/Com	pare/PWM Re	egister 2 (LSB))					XXXX XXXX	uuuu uuuu
299h	CCPR2H ⁽¹⁾	Capture/Com	pare/PWM Re	egister 2 (MSB	5)					xxxx xxxx	uuuu uuuu

CCP2M3

P2DC3

PSS2AC1

STR2D

C2TSEL1

DC2B0

P2DC4

CCP2AS0

STR2SYNC

C3TSEL0

CCP2M2

P2DC2

PSS2AC0

STR2C

C2TSEL0

CCP2M1

P2DC1

PSS2BD1

STR2B

C1TSEL1

CCP2M0

P2DC0

PSS2BD0

STR2A

C1TSEL0

0000 0000

0000 0000

0000 0000

0000 0000

--0 0001 0000 0000

0000 0000

0000 0000

0000 0000

--0

0001

Legend: x = unknown, u = unchanged, q = value depends on condition, - = unimplemented, r = reserved. Shaded locations are unimplemented, read as '0'.

DC2B1

P2DC5

CCP2AS1

C3TSEL1

P2M0

P2DC6

CCP2AS2

C4TSEL0

Note 1: PIC16(L)F1827 only.

CCP2CON⁽¹⁾

PWM2CON⁽¹⁾

CCP2AS⁽¹⁾

PSTR2CON⁽¹⁾

CCPTMRS⁽¹⁾

P2M1

P2RSEN

CCP2ASE

C4TSEL1

Unimplemented

29Ah

29Bh

29Ch

29Dh

29Eh

29Fh

5.2.1.5 TIMER1 Oscillator

The Timer1 Oscillator is a separate crystal oscillator that is associated with the Timer1 peripheral. It is optimized for timekeeping operations with a 32.768 kHz crystal connected between the T1OSO and T1OSI device pins.

The Timer1 Oscillator can be used as an alternate system clock source and can be selected during run-time using clock switching. Refer to **Section 5.3 "Clock Switching"** for more information.

FIGURE 5-5: QUARTZ CRYSTAL OPERATION (TIMER1 OSCILLATOR)



- Note 1: Quartz crystal characteristics vary according to type, package and manufacturer. The user should consult the manufacturer data sheets for specifications and recommended application.
 - 2: Always verify oscillator performance over the VDD and temperature range that is expected for the application.
 - **3:** For oscillator design assistance, reference the following Microchip Applications Notes:
 - AN826, "Crystal Oscillator Basics and Crystal Selection for rfPIC[®] and PIC[®] Devices" (DS00826)
 - AN849, "Basic PIC[®] Oscillator Design" (DS00849)
 - AN943, "Practical PIC[®] Oscillator Analysis and Design" (DS00943)
 - AN949, "Making Your Oscillator Work" (DS00949)
 - TB097, "Interfacing a Micro Crystal MS1V-T1K 32.768 kHz Tuning Fork Crystal to a PIC16F690/SS" (DS91097)
 - AN1288, "Design Practices for Low-Power External Oscillators" (DS01288)

5.2.1.6 External RC Mode

The external Resistor-Capacitor (RC) modes support the use of an external RC circuit. This allows the designer maximum flexibility in frequency choice while keeping costs to a minimum when clock accuracy is not required.

The RC circuit connects to OSC1. OSC2/CLKOUT is available for general purpose I/O or CLKOUT. The function of the OSC2/CLKOUT pin is determined by the state of the CLKOUTEN bit in Configuration Word 1.

Figure 5-6 shows the external RC mode connections.



The RC oscillator frequency is a function of the supply voltage, the resistor (REXT) and capacitor (CEXT) values and the operating temperature. Other factors affecting the oscillator frequency are:

- · threshold voltage variation
- component tolerances
- · packaging variations in capacitance

The user also needs to take into account variation due to tolerance of external RC components used.

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7.10 Determining the Cause of a Reset

Upon any Reset, multiple bits in the STATUS and PCON register are updated to indicate the cause of the Reset. Table 7-3 and Table 7-4 show the Reset conditions of these registers.

STKOVF	STKUNF	RMCLR	RI	POR	BOR	то	PD	Condition
0	0	1	1	0	x	1	1	Power-on Reset
0	0	1	1	0	x	0	x	Illegal, $\overline{\text{TO}}$ is set on $\overline{\text{POR}}$
0	0	1	1	0	x	x	0	Illegal, PD is set on POR
0	0	1	1	u	0	1	1	Brown-out Reset
u	u	u	u	u	u	0	u	WDT Reset
u	u	u	u	u	u	0	0	WDT Wake-up from Sleep
u	u	u	u	u	u	1	0	Interrupt Wake-up from Sleep
u	u	0	u	u	u	u	u	MCLR Reset during normal operation
u	u	0	u	u	u	1	0	MCLR Reset during Sleep
u	u	u	0	u	u	u	u	RESET Instruction Executed
1	u	u	u	u	u	u	u	Stack Overflow Reset (STVREN = 1)
u	1	u	u	u	u	u	u	Stack Underflow Reset (STVREN = 1)

TABLE 7-3: RESET STATUS BITS AND THEIR SIGNIFICANCE

TABLE 7-4: RESET CONDITION FOR SPECIAL REGISTERS⁽²⁾

Condition	Program Counter	STATUS Register	PCON Register
Power-on Reset	0000h	1 1000	00 110x
MCLR Reset during normal operation	0000h	u uuuu	uu Ouuu
MCLR Reset during Sleep	0000h	1 Ouuu	uu Ouuu
WDT Reset	0000h	0 uuuu	uu uuuu
WDT Wake-up from Sleep	PC + 1	0 Ouuu	uu uuuu
Brown-out Reset	0000h	1 luuu	00 11u0
Interrupt Wake-up from Sleep	PC + 1 ⁽¹⁾	1 Ouuu	uu uuuu
RESET Instruction Executed	0000h	u uuuu	uu u0uu
Stack Overflow Reset (STVREN = 1)	0000h	u uuuu	lu uuuu
Stack Underflow Reset (STVREN = 1)	0000h	u uuuu	ul uuuu

Legend: u = unchanged, x = unknown, - = unimplemented bit, reads as '0'.

Note 1: When the wake-up is due to an interrupt and Global Enable bit (GIE) is set, the return address is pushed on the stack and PC is loaded with the interrupt vector (0004h) after execution of PC + 1.

2: If a Status bit is not implemented, that bit will be read as '0'.

8.0 INTERRUPTS

The interrupt feature allows certain events to preempt normal program flow. Firmware is used to determine the source of the interrupt and act accordingly. Some interrupts can be configured to wake the MCU from Sleep mode.

This chapter contains the following information for Interrupts:

- Operation
- Interrupt Latency
- Interrupts During Sleep
- INT Pin
- · Automatic Context Saving

Many peripherals produce Interrupts. Refer to the corresponding chapters for details.

A block diagram of the interrupt logic is shown in Figure 8-1.





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8.6.5 PIE4 REGISTER⁽¹⁾

The PIE4 register contains the interrupt enable bits, as shown in Register 8-5.

- **Note 1:** The PIE4 register is available only on the PIC16(L)F1827 device.
 - 2: Bit PEIE of the INTCON register must be set to enable any peripheral interrupt.

REGISTER 8-5: PIE4: PERIPHERAL INTERRUPT ENABLE REGISTER 4⁽¹⁾

U-0	U-0	U-0	U-0	U-0	U-0	R/W-0/0	R/W-0/0
—	—	—	—	—	—	BCL2IE	SSP2IE
bit 7							bit 0

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

bit 7-2	Unimplemented: Read as '0'
bit 1	BCL2IE: MSSP2 Bus Collision Interrupt Enable bit
	1 = Enables the MSSP2 Bus Collision Interrupt0 = Disables the MSSP2 Bus Collision Interrupt
bit 0	SSP2IE: Master Synchronous Serial Port 2 (MSSP2) Interrupt Enable bit
	1 = Enables the MSSP2 interrupt0 = Disables the MSSP2 interrupt

Note 1: This register is only available on PIC16(L)F1827.

9.0 POWER-DOWN MODE (SLEEP)

The Power-Down mode is entered by executing a SLEEP instruction.

Upon entering Sleep mode, the following conditions exist:

- 1. WDT will be cleared but keeps running, if enabled for operation during Sleep.
- 2. PD bit of the STATUS register is cleared.
- 3. $\overline{\text{TO}}$ bit of the STATUS register is set.
- 4. CPU clock is disabled.
- 5. 31 kHz LFINTOSC is unaffected and peripherals that operate from it may continue operation in Sleep.
- 6. Timer1 oscillator is unaffected and peripherals that operate from it may continue operation in Sleep.
- 7. ADC is unaffected, if the dedicated FRC clock is selected.
- 8. Capacitive Sensing oscillator is unaffected.
- I/O ports maintain the status they had before SLEEP was executed (driving high, low or highimpedance).
- 10. Resets other than WDT are not affected by Sleep mode.

Refer to individual chapters for more details on peripheral operation during Sleep.

To minimize current consumption, the following conditions should be considered:

- I/O pins should not be floating
- External circuitry sinking current from I/O pins
- · Internal circuitry sourcing current from I/O pins
- · Current draw from pins with internal weak pull-ups
- Modules using 31 kHz LFINTOSC
- Modules using Timer1 oscillator

I/O pins that are high-impedance inputs should be pulled to VDD or Vss externally to avoid switching currents caused by floating inputs.

Examples of internal circuitry that might be sourcing current include modules such as the DAC and FVR modules. See Section 17.0 "Digital-to-Analog Converter (DAC) Module" and Section 14.0 "Fixed Voltage Reference (FVR)" for more information on these modules.

9.1 Wake-up from Sleep

The device can wake-up from Sleep through one of the following events:

- 1. External Reset input on MCLR pin, if enabled
- 2. BOR Reset, if enabled
- 3. POR Reset
- 4. Watchdog Timer, if enabled
- 5. Any external interrupt
- 6. Interrupts by peripherals capable of running during Sleep (see individual peripheral for more information)

The first three events will cause a device Reset. The last three events are considered a continuation of program execution. To determine whether a device Reset or wake-up event occurred, refer to **Section 7.10 "Determining the Cause of a Reset"**.

When the SLEEP instruction is being executed, the next instruction (PC + 1) is prefetched. For the device to wake-up through an interrupt event, the corresponding interrupt enable bit must be enabled. Wake-up will occur regardless of the state of the GIE bit. If the GIE bit is disabled, the device continues execution at the instruction after the SLEEP instruction. If the GIE bit is enabled, the device executes the instruction after the SLEEP instruction, the device will then call the Interrupt Service Routine. In cases where the execution of the instruction following SLEEP is not desirable, the user should have a NOP after the SLEEP instruction.

The WDT is cleared when the device wakes up from Sleep, regardless of the source of wake-up.

11.3.2 ERASING FLASH PROGRAM MEMORY

While executing code, program memory can only be erased by rows. To erase a row:

- 1. Load the EEADRH:EEADRL register pair with the address of new row to be erased.
- 2. Clear the CFGS bit of the EECON1 register.
- 3. Set the EEPGD, FREE, and WREN bits of the EECON1 register.
- 4. Write 55h, then AAh, to EECON2 (Flash programming unlock sequence).
- 5. Set control bit WR of the EECON1 register to begin the erase operation.
- 6. Poll the FREE bit in the EECON1 register to determine when the row erase has completed.

See Example 11-4.

After the "BSF EECON1, WR" instruction, the processor requires two cycles to set up the erase operation. The user must place two NOP instructions after the WR bit is set. The processor will halt internal operations for the typical 2 ms erase time. This is not Sleep mode as the clocks and peripherals will continue to run. After the erase cycle, the processor will resume operation with the third instruction after the EECON1 write instruction.

11.3.3 WRITING TO FLASH PROGRAM MEMORY

Program memory is programmed using the following steps:

- 1. Load the starting address of the word(s) to be programmed.
- 2. Load the write latches with data.
- 3. Initiate a programming operation.
- 4. Repeat steps 1 through 3 until all data is written.

Before writing to program memory, the word(s) to be written must be erased or previously unwritten. Program memory can only be erased one row at a time. No automatic erase occurs upon the initiation of the write.

Program memory can be written one or more words at a time. The maximum number of words written at one time is equal to the number of write latches. See Figure 11-2 (block writes to program memory with 32 write latches) for more details. The write latches are aligned to the address boundary defined by EEADRL as shown in Table 11-1. Write operations do not cross these boundaries. At the completion of a program memory write operation, the write latches are reset to contain 0x3FFF. The following steps should be completed to load the write latches and program a block of program memory. These steps are divided into two parts. First, all write latches are loaded with data except for the last program memory location. Then, the last write latch is loaded and the programming sequence is initiated. A special unlock sequence is required to load a write latch with data or initiate a Flash programming operation. This unlock sequence should not be interrupted.

- 1. Set the EEPGD and WREN bits of the EECON1 register.
- 2. Clear the CFGS bit of the EECON1 register.
- Set the LWLO bit of the EECON1 register. When the LWLO bit of the EECON1 register is '1', the write sequence will only load the write latches and will not initiate the write to Flash program memory.
- 4. Load the EEADRH:EEADRL register pair with the address of the location to be written.
- 5. Load the EEDATH:EEDATL register pair with the program memory data to be written.
- Write 55h, then AAh, to EECON2, then set the WR bit of the EECON1 register (Flash programming unlock sequence). The write latch is now loaded.
- 7. Increment the EEADRH:EEADRL register pair to point to the next location.
- 8. Repeat steps 5 through 7 until all but the last write latch has been loaded.
- Clear the LWLO bit of the EECON1 register. When the LWLO bit of the EECON1 register is '0', the write sequence will initiate the write to Flash program memory.
- 10. Load the EEDATH:EEDATL register pair with the program memory data to be written.
- 11. Write 55h, then AAh, to EECON2, then set the WR bit of the EECON1 register (Flash programming unlock sequence). The entire latch block is now written to Flash program memory.

It is not necessary to load the entire write latch block with user program data. However, the entire write latch block will be written to program memory.

An example of the complete write sequence for eight words is shown in Example 11-5. The initial address is loaded into the EEADRH:EEADRL register pair; the eight words of data are loaded using indirect addressing.

U-1	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0
—				EEADR<14:8	>		
bit 7							bit 0
Legend:							
R = Readable b	oit	W = Writable	bit	U = Unimpler	nented bit, read	l as '0'	
u = Bit is uncha	anged	x = Bit is unkn	nown	-n/n = Value a	at POR and BO	R/Value at all o	ther Resets
'1' = Bit is set		'0' = Bit is clea	ared				

REGISTER 11-4: EEADRH: EEPROM ADDRESS HIGH BYTE REGISTER

bit 7 Unimplemented: Read as '1'

bit 6-0 EEADR<14:8>: Specifies the Most Significant bits for program memory address or EEPROM address

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
ANSELB	ANSB7	ANSB6	ANSB5	ANSB4	ANSB3	ANSB2	ANSB1	—	128
LATB	LATB7	LATB6	LATB5	LATB4	LATB3	LATB2	LATB1	LATB0	127
OPTION_REG	WPUEN	INTEDG	TMR0CS	TMR0SE	PSA	PS2	PS1	PS0	176
PORTB	RB7	RB6	RB5	RB4	RB3	RB2	RB1	RB0	127
TRISB	TRISB7	TRISB6	TRISB5	TRISB4	TRISB3	TRISB2	TRISB1	TRISB0	127
WPUB	WPUB7	WPUB6	WPUB5	WPUB4	WPUB3	WPUB2	WPUB1	WPUB0	128

TABLE 12-6: SUMMARY OF REGISTERS ASSOCIATED WITH PORTB

Legend: — = unimplemented locations read as '0'. Shaded cells are not used by PORTB.

13.0 INTERRUPT-ON-CHANGE

The PORTB pins can be configured to operate as Interrupt-On-Change (IOC) pins. An interrupt can be generated by detecting a signal that has either a rising edge or a falling edge. Any individual PORTB pin can be configured to generate an interrupt. The interrupt-on-change module has the following features:

- Interrupt-on-Change enable (Master Switch)
- Individual pin configuration
- Rising and falling edge detection
- Individual pin interrupt flags

Figure 13-1 is a block diagram of the IOC module.

13.1 Enabling the Module

To allow individual port pins to generate an interrupt, the IOCIE bit of the INTCON register must be set. If the IOCIE bit is disabled, the edge detection on the pin will still occur, but an interrupt will not be generated.

13.2 Individual Pin Configuration

For each port pin, a rising edge detector and a falling edge detector are present. To enable a pin to detect a rising edge, the associated IOCBPx bit of the IOCBP register is set. To enable a pin to detect a falling edge, the associated IOCBNx bit of the IOCBN register is set.

A pin can be configured to detect rising and falling edges simultaneously by setting both the IOCBPx bit and the IOCBNx bit of the IOCBP and IOCBN registers, respectively.

13.3 Interrupt Flags

The IOCBFx bits located in the IOCBF register are status flags that correspond to the Interrupt-on-change pins of the port. If an expected edge is detected on an appropriately enabled pin, then the status flag for that pin will be set, and an interrupt will be generated if the IOCIE bit is set. The IOCIF bit of the INTCON register reflects the status of all IOCBFx bits.

13.4 Clearing Interrupt Flags

The individual status flags, (IOCBFx bits), can be cleared by resetting them to zero. If another edge is detected during this clearing operation, the associated status flag will be set at the end of the sequence, regardless of the value actually being written.

In order to ensure that no detected edge is lost while clearing flags, only AND operations masking out known changed bits should be performed. The following sequence is an example of what should be performed.

EXAMPLE 13-1:

```
MOVLW 0xff
XORWF IOCBF, W
ANDWF IOCBF, F
```

13.5 Operation in Sleep

The interrupt-on-change interrupt sequence will wake the device from Sleep mode, if the IOCIE bit is set.

If an edge is detected while in Sleep mode, the IOCBF register will be updated prior to the first instruction executed out of Sleep.

FIGURE 13-1: INTERRUPT-ON-CHANGE BLOCK DIAGRAM



R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u	R/W-x/u
			ADRE	S<9:2>			
bit 7							bit 0
Legend:							
R = Readable	bit	W = Writable b	it	U = Unimpler	nented bit, read	d as '0'	
u = Bit is unch	anged	x = Bit is unkno	own	-n/n = Value a	at POR and BO	R/Value at all	other Resets
'1' = Bit is set		'0' = Bit is clea	red				

REGISTER 16-3: ADRESH: ADC RESULT REGISTER HIGH (ADRESH) ADFM = 0

bit 7-0 ADRES<9:2>: ADC Result Register bits Upper 8 bits of 10-bit conversion result

REGISTER 16-4: ADRESL: ADC RESULT REGISTER LOW (ADRESL) ADFM = 0

| R/W-x/u |
|---------|---------|---------|---------|---------|---------|---------|---------|
| ADRE | S<1:0> | — | — | — | — | — | — |
| bit 7 | | | | | | | bit 0 |

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

bit 7-6 ADRES<1:0>: ADC Result Register bits Lower 2 bits of 10-bit conversion result bit 5-0 Reserved: Do not use.

19.0 COMPARATOR MODULE

Comparators are used to interface analog circuits to a digital circuit by comparing two analog voltages and providing a digital indication of their relative magnitudes. Comparators are very useful mixed signal building blocks because they provide analog functionality independent of program execution. The analog comparator module includes the following features:

- · Independent comparator control
- Programmable input selection
- · Comparator output is available internally/externally
- Programmable output polarity
- Interrupt-on-change
- · Wake-up from Sleep
- Programmable Speed/Power optimization
- · PWM shutdown
- · Programmable and fixed voltage reference

19.1 Comparator Overview

A single comparator is shown in Figure 19-1 along with the relationship between the analog input levels and the digital output. When the analog voltage at VIN+ is less than the analog voltage at VIN-, the output of the comparator is a digital low level. When the analog voltage at VIN+ is greater than the analog voltage at VIN-, the output of the comparator is a digital high level.

FIGURE 19-1: S

SINGLE COMPARATOR



19.3 Comparator Hysteresis

A selectable amount of separation voltage can be added to the input pins of each comparator to provide a hysteresis function to the overall operation. Hysteresis is enabled by setting the CxHYS bit of the CMxCON0 register.

See **Section 29.0 "Electrical Specifications"** for more information.

19.4 Timer1 Gate Operation

The output resulting from a comparator operation can be used as a source for gate control of Timer1. See **Section 21.6 "Timer1 Gate"** for more information. This feature is useful for timing the duration or interval of an analog event.

It is recommended that the comparator output be synchronized to Timer1. This ensures that Timer1 does not increment while a change in the comparator is occurring.

19.4.1 COMPARATOR OUTPUT SYNCHRONIZATION

The output from either comparator, C1 or C2, can be synchronized with Timer1 by setting the CxSYNC bit of the CMxCON0 register.

Once enabled, the comparator output is latched on the falling edge of the Timer1 source clock. If a prescaler is used with Timer1, the comparator output is latched after the prescaling function. To prevent a race condition, the comparator output is latched on the falling edge of the Timer1 clock source and Timer1 increments on the rising edge of its clock source. See the Comparator Block Diagrams (Figure 19-2 and Figure 19-3) and the Timer1 Block Diagram (Figure 21-1) for more information.

19.5 Comparator Interrupt

An interrupt can be generated upon a change in the output value of the comparator for each comparator, a rising edge detector and a Falling edge detector are present.

When either edge detector is triggered and its associated enable bit is set (CxINTP and/or CxINTN bits of the CMxCON1 register), the Corresponding Interrupt Flag bit (CxIF bit of the PIR2 register) will be set.

To enable the interrupt, you must set the following bits:

- CxON, CxPOL and CxSP bits of the CMxCON0 register
- CxIE bit of the PIE2 register
- CxINTP bit of the CMxCON1 register (for a rising edge detection)
- CxINTN bit of the CMxCON1 register (for a falling edge detection)
- · PEIE and GIE bits of the INTCON register

The associated interrupt flag bit, CxIF bit of the PIR2 register, must be cleared in software. If another edge is detected while this flag is being cleared, the flag will still be set at the end of the sequence.

Note: Although a comparator is disabled, an interrupt can be generated by changing the output polarity with the CxPOL bit of the CMxCON0 register, or by switching the comparator on or off with the CxON bit of the CMxCON0 register.

19.6 Comparator Positive Input Selection

Configuring the CxPCH<1:0> bits of the CMxCON1 register directs an internal voltage reference or an analog pin to the non-inverting input of the comparator:

- C1IN+ or C2IN+ analog pin
- DAC
- FVR (Fixed Voltage Reference)
- · Vss (Ground)

See Section 14.0 "Fixed Voltage Reference (FVR)" for more information on the Fixed Voltage Reference module.

See Section 17.0 "Digital-to-Analog Converter (DAC) Module" for more information on the DAC input signal.

Any time the comparator is disabled (CxON = 0), all comparator inputs are disabled.

21.12 Timer1 Gate Control Register

The Timer1 Gate Control register (T1GCON), shown in Register 21-2, is used to control Timer1 gate.

R/W-0/u	R/W-0/u	R/W-0/u	R/W-0/u	R/W/HC-0/u	R-x/x	R/W-0/u	R/W-0/u	
TMR1GE	T1GPOL	T1GTM	T1GSPM	T1GGO/ DONE	T1GVAL	T1GSS	5<1:0>	
bit 7							bit 0	
Legend:								
R = Readable	bit	W = Writable	bit	U = Unimplen	nented bit, read	d as '0'		
u = Bit is uncha	anged	x = Bit is unkr	Iown	-n/n = Value a	at POR and BO	R/Value at all o	ther Resets	
'1' = Bit is set		'0' = Bit is clea	ared	HC = Bit is cle	eared by hardw	/are		
bit 7 TMR1GE: Timer1 Gate Enable bit <u>If TMR1ON = 0</u> : This bit is ignored <u>If TMR1ON = 1</u> : 1 = Timer1 counting is controlled by the Timer1 gate function								
bit 6	T1GPOL: Tim 1 = Timer1 ga 0 = Timer1 ga	ner1 Gate Pola ate is active-hig ate is active-lov	rity bit gh (Timer1 cou w (Timer1 cou	unts when gate nts when gate i	is high) s low)			
bit 5	T1GTM: Time 1 = Timer1 G 0 = Timer1 G Timer1 gate fl	r1 Gate Toggle ate Toggle mo ate Toggle mo ip-flop toggles	e Mode bit de is enabled de is disabled on every rising	and toggle flip- g edge.	flop is cleared			
bit 4	T1GSPM: Tin	ner1 Gate Sing	le-Pulse Mode	e bit				
	1 = Timer1 ga 0 = Timer1 ga	ate Single-Puls ate Single-Puls	e mode is ena e mode is disa	bled and is cor abled	ntrolling Timer1	gate		
bit 3	T1GGO/DON	E: Timer1 Gate	e Single-Pulse	Acquisition Sta	atus bit			
	1 = Timer1 ga 0 = Timer1 ga	ate single-pulse ate single-pulse	e acquisition is e acquisition h	ready, waiting as completed c	for an edge or has not been	started		
bit 2	T1GVAL: Tim	er1 Gate Curre	ent State bit					
	Indicates the Unaffected by	current state of Timer1 Gate E	f the Timer1 ga Enable (TMR1)	ate that could b GE).	e provided to T	MR1H:TMR1L.		
bit 1-0	T1GSS<1:0>	: Timer1 Gate	Source Select	bits				
	00 = Timer1 gate pin 01 = Timer0 overflow output 10 = Comparator 1 optionally synchronized output (SYNCC1OUT) 11 = Comparator 2 optionally synchronized output (SYNCC2OUT)							

REGISTER 21-2: T1GCON: TIMER1 GATE CONTROL REGISTER

R/W-1/1	R/W-1/1	R/W-1/1	R/W-1/1	R/W-1/1	R/W-1/1	R/W-1/1	R/W-1/1			
			MSK	<7:0>						
bit 7							bit 0			
Legend:										
R = Readable bit W = Writable bit			bit	U = Unimplemented bit, read as '0'						
u = Bit is uncl	nanged	x = Bit is unki	nown	-n/n = Value at POR and BOR/Value at all other Resets						
'1' = Bit is set		'0' = Bit is cle	ared							
bit 7-1	MSK<7:1>:	Mask bits								
1 = The received address bit n is compared to SSPxADD <n> to detect I²C address match</n>										
	0 = The rec	eived address b	it n is not use	d to detect I ² C	address match					
bit 0	bit 0 MSK<0>: Mask bit for I ² C Slave mode, 10-bit Address									

REGISTER 25-5: SSPxMSK: SSPx MASK REGISTER

- I^2C Slave mode, 10-bit address (SSPxM<3:0> = 0111 or 1111): 1 = The received address bit 0 is compared to SSPxADD<0> to detect I^2C address match
 - 0 = The received address bit 0 is not used to detect I²C address match
- I²C Slave mode, 7-bit address, the bit is ignored

REGISTER 25-6: SSPxADD: MSSPx ADDRESS AND BAUD RATE REGISTER (I²C MODE)

R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	
ADD<7:0>								
bit 7								

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

Master mode:

bit 7-0	ADD<7:0>: Baud Rate Clock Divider bits
	SCLx pin clock period = ((ADD<7:0> + 1) *4)/Fosc

<u>10-Bit Slave mode — Most Significant Address byte:</u>

- bit 7-3 **Not used:** Unused for Most Significant Address byte. Bit state of this register is a "don't care". Bit pattern sent by master is fixed by I²C specification and must be equal to '11110'. However, those bits are compared by hardware and are not affected by the value in this register.
- bit 2-1 ADD<2:1>: Two Most Significant bits of 10-bit address
- bit 0 Not used: Unused in this mode. Bit state is a "don't care".

<u>10-Bit Slave mode — Least Significant Address byte:</u>

bit 7-0 ADD<7:0>: Eight Least Significant bits of 10-bit address

7-Bit Slave mode:

bit 7-1	ADD<7:1>: 7-bit address

bit 0 Not used: Unused in this mode. Bit state is a "don't care".

26.2 Clock Accuracy with Asynchronous Operation

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The factory calibrates the internal oscillator block output (INTOSC). However, the INTOSC frequency may drift as VDD or temperature changes, and this directly affects the asynchronous baud rate. Two methods may be used to adjust the baud rate clock, but both require a reference clock source of some kind. The first (preferred) method uses the OSCTUNE register to adjust the INTOSC output. Adjusting the value in the OSCTUNE register allows for fine resolution changes to the system clock source. See **Section 5.2.2** "Internal Clock Sources" for more information.

The other method adjusts the value in the Baud Rate Generator. This can be done automatically with the Auto-Baud Detect feature (see **Section 26.3.1 "Auto-Baud Detect"**). There may not be fine enough resolution when adjusting the Baud Rate Generator to compensate for a gradual change in the peripheral clock frequency.

REGISTER 26-1: TXSTA: TRANSMIT STATUS AND CONTROL REGISTER

R/W-/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R/W-0/0	R-1/1	R/W-0/0	
CSRC	TX9	TXEN ⁽¹⁾	SYNC	SENDB	BRGH	TRMT	TX9D	
bit 7							bit 0	
Legend:								
R = Readable	e bit	W = Writable b	it	U = Unimpleme	ented bit, read as	'0'		
u = Bit is unc	hanged	x = Bit is unkno	own	-n/n = Value at	POR and BOR/Va	alue at all other	Resets	
'1' = Bit is set	t	'0' = Bit is clear	red					
bit 7	CSRC: Clock S	Source Select bit						
	Asynchronous	mode:						
	Don't care	ada						
	1 = Master m	<u>ioue</u> . Iode (clock gene	rated internally	from BRG)				
	0 = Slave mo	de (clock from e	xternal source)					
bit 6	TX9: 9-bit Tran	smit Enable bit						
	1 = Selects 9	-bit transmission	I					
	0 = Selects 8	-bit transmission	I					
bit 5	TXEN: Transm	it Enable bit ⁽¹⁾						
	1 = Transmit e	enabled						
bit 4		uisabieu PT Modo Soloot k						
DIL 4	1 = Synchrony	nus mode	JIL					
	0 = Asynchror	nous mode						
bit 3	SENDB: Send	Break Character	r bit					
	Asynchronous	mode:						
	1 = Send Sync Break on next transmission (cleared by hardware upon completion)							
	0 = Sync Brea	ak transmission (hode:	completed					
	Don't care	<u>1000</u> .						
bit 2	BRGH: High B	aud Rate Select	bit					
	Asynchronous	<u>mode</u> :						
	1 = High spee	d						
	0 = Low spee	d						
	Unused in this	mode						
bit 1	TRMT: Transm	it Shift Register :	Status bit					
~	1 = TSR empt	ty						
	0 = TSR full	-						
bit 0	TX9D: Ninth bi	t of Transmit Dat	ta					
	Can be addres	s/data bit or a pa	arity bit.					
Note 1: S	SREN/CREN overrid	les TXEN in Syn	c mode.					

30.3 DC Characteristics: PIC16(L)F1826/27-I/E (Power-Down) (Continued)

PIC16LF1826/27			$\begin{array}{llllllllllllllllllllllllllllllllllll$						
PIC16F1826/27			Standa Operati	$\begin{array}{l} \mbox{tandard Operating Conditions (unless otherwise stated)} \\ \mbox{operating temperature} & -40^{\circ}C \leq TA \leq +85^{\circ}C \mbox{ for industrial} \\ -40^{\circ}C \leq TA \leq +125^{\circ}C \mbox{ for extended} \end{array}$					
Param	Device Characteristics	Min.	Typt	Max.	Max.	Units		Conditions	
NO.				+85°C	+125°C		VDD	Note	
	Power-down Base Current	(IPD) ⁽²⁾	1	1	1	1	1		
D026A*		_	250	—	—	μA	1.8	A/D Current (Note 1, Note 3),	
		-	250	—	_	μA	3.0	conversion in progress	
D026A*			280	—	—	μA	1.8	A/D Current (Note 1, Note 3),	
		_	280			μΑ	3.0		
		—	280	_	-	μΑ	5.0		
D027			3.5	6	8	μΑ	1.8	Cap Sense Low Power Oscillator mode (Note 1)	
D027		_	1	10	14	μΑ	3.0		
D027			4.3	30	38	μΑ	1.8	Oscillator mode (Note 1)	
			0.0	39	42	μΑ	5.0		
D027A		_	0.3	42	43	μΑ	1.8	Can Sense Medium Power	
DUZTA			4.2	12	10	μΑ	3.0	Oscillator mode (Note 1)	
D027A			74	38	40	μΑ	1.8	Can Sense Medium Power	
DOLIN			97	42	43	μΑ	3.0	Oscillator mode (Note 1)	
			10.4	46	48	μΑ	5.0	-	
D027B		_	6	10	15	μA	1.8	Cap Sense High Power	
-		_	10	14	20	μA	3.0	Oscillator mode (Note 1)	
D027B		_	17	44	50	μA	1.8	Cap Sense High Power	
		_	41	68	80	μA	3.0	Oscillator mode (Note 1)	
		_	50	78	90	μA	5.0	1	
D028		_	6.9	11	15	μA	1.8	Comparator Current, Low Power	
			7.0	13	16	μA	3.0	mode, one comparator enabled (Note 1)	
D028			24	45	60	μA	1.8	Comparator Current, Low Power	
		_	24.5	60	70	μA	3.0	mode, one comparator enabled	
		—	25	65	75	μA	5.0		
D028A		_	7.0	12	16	μA	1.8	Comparator Current, Low Power	
		_	7.2	14	17	μΑ	3.0	(Note 1)	
D028A		_	24	45	60	μA	1.8	Comparator Current, Low Power	
		_	24.5	60	70	μA	3.0	mode, two comparators enabled	
		-	25	65	75	μA	5.0		

These parameters are characterized but not tested.

† Data in "Typ" column is at 3.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: The peripheral current is the sum of the base IDD or IPD and the additional current consumed when this peripheral is enabled. The peripheral △ current can be determined by subtracting the base IDD or IPD current from this limit. Max values should be used when calculating total current consumption.

2: The power-down current in Sleep mode does not depend on the oscillator type. Power-down current is measured with the part in Sleep mode, with all I/O pins set to inputs state and tied to VDD.

3: A/D oscillator source is FRC.

*

30.3 DC Characteristics: PIC16(L)F1826/27-I/E (Power-Down) (Continued)

PIC16LF1826/27			$\begin{array}{llllllllllllllllllllllllllllllllllll$						
PIC16F1826/27			$\begin{array}{ll} \mbox{Standard Operating Conditions (unless other}\\ \mbox{Operating temperature} & -40^\circ C \leq TA \leq +85^\circ C\\ -40^\circ C \leq TA \leq +125^\circ C \end{array}$				erwise stated) C for industrial i°C for extended		
Param Principal Param		Min	Trent	Max.	Max.	L Inite	Conditions		
No.	Device Characteristics	WIII.	турт	+85°C	+125°C	Units	Vdd	Note	
	Power-down Base Current	(IPD) ⁽²⁾							
D028B		—	24	32	40	μA	1.8	Comparator Current, High Power	
		—	25	35	45	μA	3.0 mode, c (Note 1)	mode, one comparator enabled (Note 1)	
D028B		_	36	60	80	μA	1.8	Comparator Current, High Power	
		_	37	63	87	μA	3.0	mode, one comparator enabled	
		—	38	65	90	μA	5.0	(Note I)	
D028C		_	40	80	90	μA	1.8	Comparator Current, High Power	
		—	41	83	95	μA	3.0	mode, two comparators enabled	
D028C		_	43	86	100	μA	1.8	Comparator Current, High Power	
		_	44	90	105	μA	3.0	mode, two comparators enabled	
		_	45	95	110	μA	5.0		

* These parameters are characterized but not tested.

† Data in "Typ" column is at 3.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: The peripheral current is the sum of the base IDD or IPD and the additional current consumed when this peripheral is enabled. The peripheral △ current can be determined by subtracting the base IDD or IPD current from this limit. Max values should be used when calculating total current consumption.

2: The power-down current in Sleep mode does not depend on the oscillator type. Power-down current is measured with the part in Sleep mode, with all I/O pins set to inputs state and tied to VDD.

3: A/D oscillator source is FRC.

18-Lead Plastic Small Outline (SO) - Wide, 7.50 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-051C Sheet 1 of 2